









	<h2 style="color: orange;">FQU3N60CTU</h2>
	<p>Hersteller-Teilenummer: FQU3N60CTU</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 600V 2.4A IPAK</p> <p>Datenblätter:  FQU3N60CTU.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 5000 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen	
Teilenummer	FQU3N60CTU
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 600V 2.4A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	5000 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	50W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.4A (Tc)
Rds On (Max) @ Id, Vgs	3.4 Ohm @ 1.2A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	14nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	565pF @ 25V
Verpackung	Tube



















































FQU3N60CTU ist neu im Original, Suche FQU3N60CTU Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQU3N60CTU Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQU3N60CTU: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQU3N50CTU Fairchild/ON Semiconductor MOSFET N-CH 500V 2.5A IPAK</p>	 <p>FQU3P20TU Fairchild/ON Semiconductor MOSFET P-CH 200V 2.4A IPAK</p>	 <p>FQU3N60TU AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 2.4A IPAK</p>	 <p>FQU3N60C FSC FQU3N60C FSC</p>
 <p>FQU3N60TU Fairchild/ON Semiconductor MOSFET N-CH 600V 2.4A IPAK</p>	 <p>FQU3N60CTU AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 2.4A IPAK</p>	 <p>FQU3N50CTU AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 2.5A IPAK</p>	 <p>FQU3N50C FAIRCHI FQU3N50C FAIRCHI</p>

heiße Teile

Mehr

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|--|--|--|---|--|
|  FQU1N80TU |  FQU20N06 |  FQU20N06L |  FQU20N06LTU |  FQU20N06LTU |
|  FQU2N50B |  FQU2N50BTU |  FQU2N50BTU |  FQU2N60/SSU2N60 |  FQU2N60A |
|  FQU2N60B |  FQU2N60C |  FQU2N60CTU |  FQU2N60CTU |  FQU2N65C |
|  FQU2N90TU |  FQU2N90TU |  FQU30N06L |  FQU3N40TU |  FQU3N40TU |
|  FQU3N50C |  FQU3N50CTU |  FQU3N50CTU |  FQU3N60C |  FQU3N60CTU |
|  FQU3N60TU |  FQU3N60TU |  FQU4N20LTU |  FQU4N20TU |  FQU4N20TU |
|  FQU4N25TU |  FQU4N25TU |  FQU4N50TU |  FQU4N50TU |  FQU4N50TU_WS |
|  FQU4N60C |  FQU4P25TU |  FQU4P25TU |  FQU5N40TU |  FQU5N40TU |
|  FQU5N50C |  FQU5N50CS |  FQU5N50CTU |  FQU5N50CTU |  FQU5N60C |
|  FQU5N60CTU |  FQU5N60CTU |  FQU5N65C |  FQU5P20TU |  FQU5P20TU |

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